

PCIe® Gen4 NVMe CFexpress Card

The Global Leader in Specialized Storage and Memory Solutions





KEY FEATURES

- Superior Read/Write performance
- Self-Encrypting Drive (SED) with AES 256-bit Encryption, TCG Opal 2.0*
- Host Memory Buffer (HMB) support
- Hardware Write Protect*
- * Optional, by project support.

ATP N751Pi / N651Si / N601Sc CFexpress Type B memory cards support the NVMe™ protocol and utilize the PCle 3.0 x2* interface. The N751Pi / N651Si/ N601Sc surpasses standard configurations and delivers impressive high-speed sequential read/write speeds of up to 3500/3200 MB/s. Built with 3D TLC flash (available with pSLC by project support) ,ATP CFexpress Type B memory cards offer big storage for IPC/embedded, automation, networking, test and measurement, and transportation systems as well as other applications that require excellent reliability, endurance, and performance.

The N751Pi / N651Si / N601Sc features Host Memory Buffer (HMB) support to improve random read performance, optional TCG Opal 2.0 and hardware write-protect security, and software RAID 0, 1 compatibility. To ensure optimal sustained performance, the N651Si / N601Sc Series CFexpress cards continuously monitor device temperature and enable firmware-based throttling that adjusts performance without drastic drops.

^{*}CFExpress spec 4.0 for PCIe Gen. 4 is under IP review and will be released Aug. 24, 2023.

Specifications

| PCIe® Gen4 NVMe CFexpress Card | | | | | | | | | |
|------------------------------------|--------------------------------------|---------|-------------|--|--|--|--|--|--|
| B 1 111 | | | | | | | | | |
| Product Line | N751Pi | | | | | | | | |
| Interface | PCIe G4 x2 | | | | | | | | |
| Flash Type | 3D TLC (pSLC mode) 3D TLC | | | | | | | | |
| Form Factor | CFexpress Type B | | | | | | | | |
| Operating Temperature | -40°C | to 85°C | 0°C to 70°C | | | | | | |
| Power Loss Protection Options | Firmware Based | | | | | | | | |
| Optional SED Features | AES 256-bit Encryption, TCG Opal 2.0 | | | | | | | | |
| Capacity | 40 GB to 320GB 128 GB to 1 TB | | | | | | | | |
| Performance | | | | | | | | | |
| Sequential Read (MB/s) up to | 3,500 | | | | | | | | |
| Sequential Write (MB/s) up to | 3,100 3,200 | | | | | | | | |
| Random Reads IOPS up to | 770,000 | | | | | | | | |
| Random Writes IOPS up to | 735,000 750,000 | | | | | | | | |
| | Endurance and Reliability | | | | | | | | |
| Endurance (TBW) ¹ up to | rance (TBW)¹ up to 19,010 TB | | 2,600 TB | | | | | | |
| Reliability MTBF @ 25°C | >2,000,000 hours | | | | | | | | |
| Reliability Number of Insertions | 10,000 minimum | | | | | | | | |
| | Others | | | | | | | | |
| Dimensions (mm) | 29.6 x 38.5 x 3.8 | | | | | | | | |
| Certifications | CE, FCC, RoHS, UKCA | | | | | | | | |
| Warranty | 5 years 2 years | | | | | | | | |

| Technolo Add-On S | ogies & Services | S.M.A.R.T. | Firmware-based Power Loss Protection | | Advanced Wear Leveling | Dynamic Data Refresh | End-to End Data Path Protection | | Secure Erase | | Industrial Temperature | Anti-Sulfur Resistors | Conformal Coating | | Joint Validation |
|----------------------|---------------------|------------|--|---|------------------------|-------------------------|------------------------------------|---|--------------|----------|---------------------------|--------------------------|----------------------|---|------------------|
| Premi | ium | 0 | 0 | 0 | 0 | 0 | 0 | 0 | A | A | 0 | A | A | 0 | A |
| Super | rior | 0 | 0 | 0 | 0 | 0 | 0 | 0 | A | A | 0 | - | A | 0 | A |

¹ Under highest Sequential write value. May vary by density, configuration and applications.

Product spec and its related information are subject to change without advance notice. Please refer to www.atpinc.com for latest information

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^{▲:} Customization option available on a project basis.